

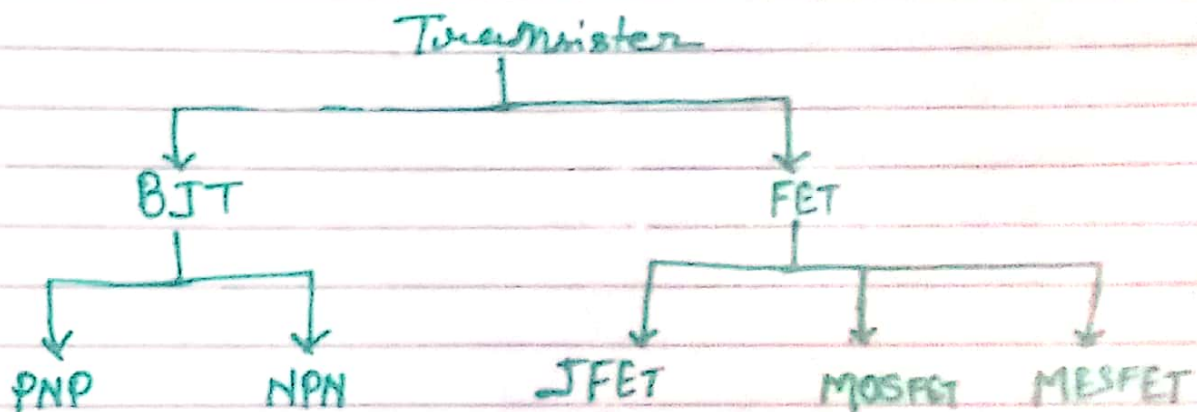
Date
20/02/2024

B.Sc 'DIII'
VI 'B'

Transistor →

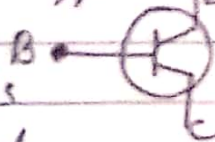
A transistor is a miniature device that is used to control or regulate the flow of electronic signals. (Basically it acts as a switch and amplifier). It is a type of semiconductor device.

Type of transistor →



BJT (Bipolar Junction Transistor) → It is a current controlled device. A BJT consists of three differently doped regions. They can have the configuration of NPN or PNP and the various layers can either be parallel or perpendicular to the surface. Consider a PNP BJT, with three differently doped regions.

(a) **Emitter region** - This is usually a heavily doped region (P^+). The emitter 'emits' the carriers into the base.



(b) **Base region** → This is lightly doped n-region. The base region is also physically thin so that carriers can pass through with minimal recombination.

③ Collector region \rightarrow This is a P-type region. The collector region has a larger width than the other two regions since charge is accumulated here from the base.

Thus a transistor consists of two PN junctions, each with its own depletion region.

(i) Emitter base junction \rightarrow Since the emitter is usually heavily doped the depletion region lies almost entirely in the base.

(ii) Base collector junction \rightarrow The depletion region at this junction is usually divided between base and collector since they are comparably doped.

There are three different configurations in which the BJT can function - Common base, common emitter and common collector.

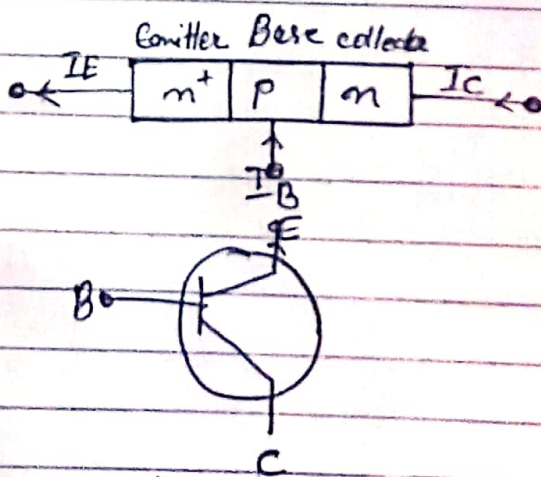


Fig of 'nnp' BJT

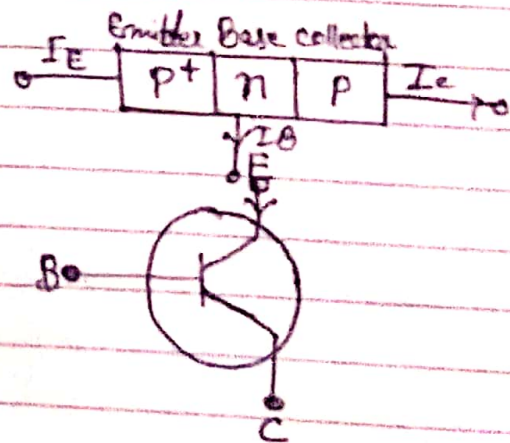


Fig of 'pnp' BJT

The BJT consists of three regions emitter, base and collector. The emitter and collector are usually of one type of doping. The base is another doping type.